

Serial No.: 09/471,460

Filed: December 22, 1999

For: USE OF A PLASMA SOURCE TO

FORM A LAYER DURING THE

FORMATION OF A SEMICONDUCTOR

Patent 2825 Group Art Unit: Examiner: Calvin Lee 94-0280.03 Atty. Docket:

> Certificate of Mailing (37 C.F.R.§ 1.8) I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail, postage prepaid, in an envelope addressed to Commissioner for Patents; Washington, D.C. 20231, on the date below:

PETITION FOR EXTENSION OF TIME UNDER 37 C.F.R. § 1.136(a)

§ § §

Commissioner for Patents Washington, D.C. 20231

Dear Sir:

Applicant hereby petitions to extend the period for response to the Office Action mailed November 21, 2000 for three (3) months, from 2/21/01 to 5/21/01.

Accordingly, the requisite fee is \$890. The Commissioner is requested to charge this fee, and any additional fee which may be required to Micron Technology, Inc. Deposit Account 13-3092, Order No. 94-0280.03. A duplicate copy of this petition is enclosed.

Respectfully submitted,

Charles Brown

Date: 5/21 \

05/31/2001 SMINASS1 00000046 133092 09471460 890.00 CH 01 FC:117

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